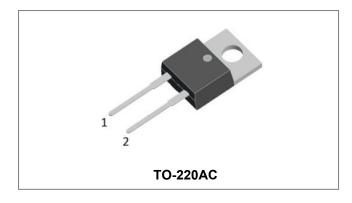






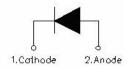
MUR1560 ULTRAFAST RECTIFIER



Features

- Ultra-Fast Switching
- High Current Capability
- Low Reverse Leakage Current
- High Surge Current Capability
- Plastic Material has UL Flammability Classification 94V-O
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Circuit Diagram



Applications

- Switching Power Supply
- Power Switching Circuits
- General Purpose

Maximum Ratings:

Characteristics	Symbol	Condition	Max.		Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	$egin{array}{c} V_{RRM} \ V_{RWM} \ V_{R} \end{array}$	-	600		V
Average Rectified Forward Current	I _{F (AV)}	50% duty cycle @T _C =100°C, rectangular wave form	15		Α
Peak One Cycle Non-Repetitive Surge		9.2mg Holf Cine pulse	T _J =45°C 1		^
Current	IFSM	8.3ms, Half Sine pulse	T _J =150°C	95	1 A

Electrical Characteristics:

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop*	V _{F1}	@ 15A, Pulse, T _J = 25°C	1.35	1.7	V
	V _{F2}	@ 15A, Pulse, T _J = 150°C	-	1.5	V
Reverse Current*	I _{R1}	$@V_R = rated V_R$ $T_J = 25^{\circ}C$	0.03	25	μA
	I _{R2}	$@V_R = rated V_R$ $T_J = 125^{\circ}C$	0.005	1	mA
Reverse Recovery Time	t _{rr}	I _F =500mA, I _R =1A,and I _m =250mA	43	50	ns

^{*} Pulse width < 300 µs, duty cycle < 2%

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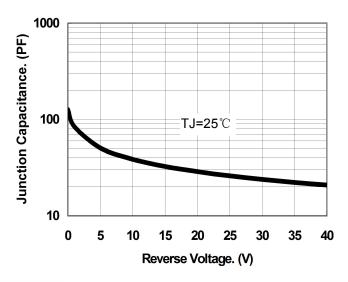




Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T _{stg}	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case	R _θ Jc	DC operation	1.5	°C/W
Approximate Weight	wt	-	1.6	g
Case Style	TO-220AC			

Ratings and Characteristics Curves



100 Instantaneous Reverse Current. (µ A) 10 TJ=125℃ 0.1 TJ=25℃ 0.01 0.001 20 30 40 50 60 70 80 90 Percent Of Rated Peak Reverse Voltage. (%)

Fig.1-Typical Junction Capacitance

Fig.2-Typical Reverse Characteristics

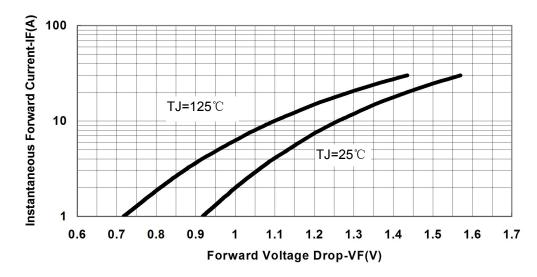


Fig.3-Typical Forward Voltage Drop Characteristics

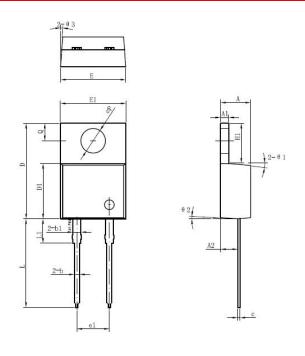
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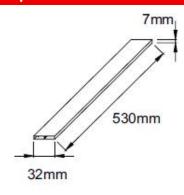


Mechanical Dimensions TO-220AC



Symbol	Dimensions in millimeters				
	Min.	Typical	Max.		
Α	4.47	4.70	4.85		
A1	1.17	1.27	1.37		
A2	2.52	2.69	2.89		
b	0.71	0.81	0.96		
b1	1.17	1.27	1.37		
С	0.31	0.38	0.61		
D	14.64	14.94	15.24		
D1	8.50	8.07	8.90		
Е	10.01	10.16	10.31		
E1	9.98	10.18	10.38		
e1	4.98	5.08	5.18		
H1	6.04	6.24	6.44		
L	13.00	13.86	14.08		
L1	3.56	3.80	3.96		
ФР	3.74	3.84	4.04		
Q	2.54	2.74	2.94		
Θ1		5°			
Θ2		4°			
Θ3		4°			

Tube Specification



Marking Diagram



Where XXXXX is YYWWL

MUR = Device Type 15 = Forward Current (15A) 60 = Reverse Voltage(600V)

 SSG
 = SSG

 YY
 = Year

 WW
 = Week

 L
 = Lot Number

Cautions: Molding resin

Epoxy resin UL:94V-0

Ordering Information

Device	Package	Shipping	
MUR1560	TO-220AC (Pb-Free)	50 pcs/ tube	

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

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